

### Features

- Wide supply voltage range from 0.9V to 3.6V
- Inputs accept voltages up to 3.6V
- I<sub>OFF</sub> supports partial-power-down mode
- Low static power consumption; I<sub>CC</sub>=0.5μA (Max.)
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

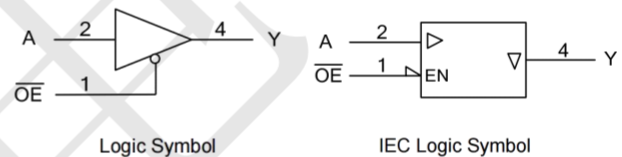
### General Description

The NC7SV125P5X-TP is a single bus buffer/line driver with 3-state output. When the output enable (OE) is high the output will be disabled. In contrast, when the OE is low, true data will pass from A input to the Y output.

### Applications

- AV Receiver
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- Personal Digital Assistant(PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive(SSD): Client and Enterprise
- Wireless Headset, Keyboard, and Mouse

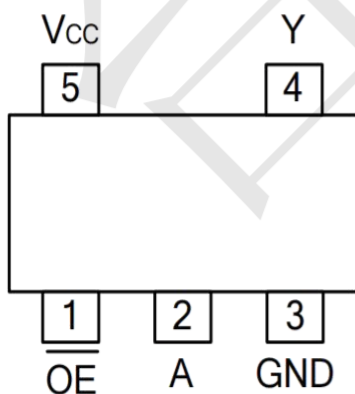
### Logic Diagram



### Ordering Information

ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION
NC7SV125P5X-TP	SOT353	Tape and Reel, 3000

### Pin Configuratio (TOP VIEW)



SOT353

### Function Table (each gate)

INPUT(OE)	INPUT(A)	OUTPUT(Y)
L	L	L
L	H	H
H	X	Z

H: HIGH voltage level; L: LOW voltage level;  
X=don't care; Z=high-impedance OFF-state.

### Absolute Maximum Ratings

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Supply Voltage	V <sub>CC</sub>		-0.5 ~ +4.6	V
Input Voltage	V <sub>IN</sub>		-0.5 ~ +4.6	V
Output Voltage	V <sub>OUT</sub>	Output in the high or low state	-0.5 ~ +V <sub>CC</sub> +0.5V	V
		Output in the power-off state	-0.5 ~ +4.6	V
VCC or GND Current	I <sub>CC</sub>		±50	mA
Continuous Output Current	I <sub>OUT</sub>	V <sub>OUT</sub> =0~V <sub>CC</sub>	±20	mA
Input Clamp Current	I <sub>IK</sub>	V <sub>IN</sub> <0	-50	mA
Output Clamp Current	I <sub>OK</sub>	V <sub>OUT</sub> <0	-50	mA
Storage Temperature Range	T <sub>STG</sub>		-65 ~ +150	°C
Junction to Ambient	θ <sub>JA</sub>	SOT353	280	°C/W

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V <sub>CC</sub>	Operating	0.9	--	3.6	V
Input Voltage	V <sub>IN</sub>		0	--	3.6	V
Output Voltage	V <sub>OUT</sub>	High or low state	0	--	V <sub>CC</sub>	V
Input Transition Rise or Fall Rate	Δt/Δv	V <sub>CC</sub> =0.8V ~ 3.6V	--	--	200	ns/V
Operating Temperature	T <sub>A</sub>		-40	--	+125	°C

### Electrical Characteristics (T<sub>A</sub>=25°C ,unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
High-level Input Voltage	V <sub>IH</sub>	V <sub>CC</sub> =0.9V	0.7×V <sub>CC</sub>	--	--	V	
		V <sub>CC</sub> =1.0V ~ 1.95V	0.65×V <sub>CC</sub>	--	--	V	
		V <sub>CC</sub> =2.3V ~ 2.7V	1.6	--	--	V	
		V <sub>CC</sub> =3V ~ 3.6V	2	--	--	V	
Low-level Input Voltage	V <sub>IL</sub>	V <sub>CC</sub> =0.9V	--	--	0.3×V <sub>CC</sub>	V	
		V <sub>CC</sub> =1.1V ~ 1.95V	--	--	0.35×V <sub>CC</sub>	V	
		V <sub>CC</sub> =2.3V ~ 2.7V	--	--	0.7	V	
		V <sub>CC</sub> =3V ~ 3.6V	--	--	0.9	V	
High-Level Output Voltage	V <sub>OH</sub>	V <sub>CC</sub> =0.9~ 3.6V, I <sub>OH</sub> =-20μA	V <sub>CC</sub> -0.1	--	--	V	
		V <sub>CC</sub> =1.1V, I <sub>OH</sub> =-1.1mA	0.75×V <sub>CC</sub>	--	--	V	
		V <sub>CC</sub> =1.4V, I <sub>OH</sub> =-1.7mA	1.11	--	--	V	
		V <sub>CC</sub> =1.65V, I <sub>OH</sub> =-1.9mA	1.32	--	--	V	
		V <sub>CC</sub> =2.3V	I <sub>OH</sub> =-2.3mA	2.05	--	--	V
			I <sub>OH</sub> =-3.1mA	1.9	--	--	V
		V <sub>CC</sub> =3V	I <sub>OH</sub> =-2.7mA	2.72	--	--	V
			I <sub>OH</sub> =-4mA	2.6	--	--	V
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>CC</sub> =0.9~ 3.6V, I <sub>OL</sub> =20μA	--	--	0.1	V	
		V <sub>CC</sub> =1.1V, I <sub>OL</sub> =1.1mA	--	--	0.3×V <sub>CC</sub>	V	
		V <sub>CC</sub> =1.4V, I <sub>OL</sub> =1.7mA	--	--	0.31	V	
		V <sub>CC</sub> =1.65V, I <sub>OL</sub> =1.9mA	--	--	0.31	V	
		V <sub>CC</sub> =2.3V	I <sub>OL</sub> =2.3mA	--	--	0.31	V
			I <sub>OL</sub> =3.1mA	--	--	0.44	V
		V <sub>CC</sub> =3V	I <sub>OL</sub> =2.7mA	--	--	0.31	V
			I <sub>OL</sub> =4mA	--	--	0.44	V
Input Leakage Current	I <sub>I(LEAK)</sub>	V <sub>CC</sub> =0 ~ 3.6V, V <sub>IN</sub> =GND ~ 3.6V	--	--	±0.1	μA	
Power OFF Leakage Current	I <sub>off</sub>	V <sub>CC</sub> =0 V, V <sub>IN</sub> or V <sub>OUT</sub> =0 ~ 3.6V	--	--	±0.2	μA	
Additional Power OFF Leakage Current	ΔI <sub>off</sub>	V <sub>CC</sub> =0 V~0.2V, V <sub>IN</sub> or V <sub>OUT</sub> =0 ~ 3.6V	--	--	±0.2	μA	
Quiescent Supply Current	I <sub>CC</sub>	V <sub>CC</sub> =0.9~3.6V, V <sub>IN</sub> =V <sub>CC</sub> or GND, I <sub>OUT</sub> =0	--	--	0.5	μA	
Additional Quiescent Supply Current Per Input Pin	ΔI <sub>CC</sub>	V <sub>CC</sub> =3.3 V, V <sub>IN</sub> =V <sub>CC</sub> -0.6V, I <sub>OUT</sub> =0	--	--	40	μA	
Input Capacitance	C <sub>I</sub>	V <sub>CC</sub> =0V-3.6V, V <sub>IN</sub> =V <sub>CC</sub> or GND	--	1.7	--	pF	
Output Capacitance	C <sub>OUT</sub>	V <sub>CC</sub> =0V, V <sub>OUT</sub> =GND	--	1.5	--	pF	

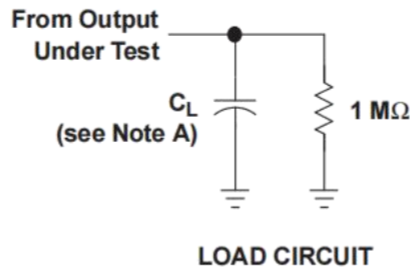
### OPERATING CHARACTERISTICS (f=10MHz, TA =25°C , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C <sub>PD</sub>	V <sub>CC</sub> =0.9V	--	2.7	--	pF
		V <sub>CC</sub> =1.2±0.1V	--	2.8	--	pF
		V <sub>CC</sub> =1.5±0.1V	--	2.9	--	pF
		V <sub>CC</sub> =1.8±0.15V	--	3.0	--	pF
		V <sub>CC</sub> =2.5±0.2V	--	3.6	--	pF
		V <sub>CC</sub> =3.3±0.3V	--	4.2	--	pF

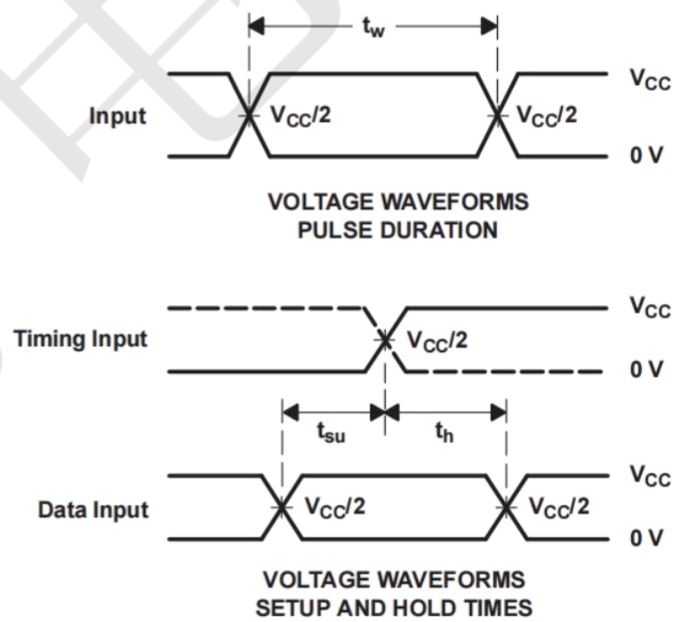
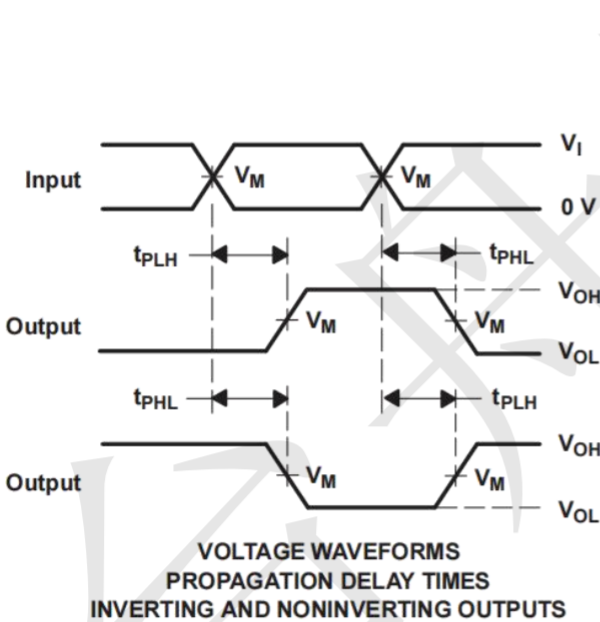
### SWITCHING CHARACTERISTICS ( TA =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Propagation delay from inputs (A) to output(Y)	t <sub>PD</sub>	CL=5pF, RL=1MΩ	V <sub>CC</sub> =0.9V	--	20.6	--	ns
			V <sub>CC</sub> =1.2±0.1V	2.8	5.5	10.5	ns
			V <sub>CC</sub> =1.5±0.1V	2.2	3.9	6.1	ns
			V <sub>CC</sub> =1.8±0.15V	1.9	3.2	4.8	ns
			V <sub>CC</sub> =2.5±0.2V	1.6	2.6	3.6	ns
			V <sub>CC</sub> =3.3±0.3V	1.4	2.4	3.1	ns
		CL=10pF, RL=1MΩ	V <sub>CC</sub> =0.9V	--	24.0	--	ns
			V <sub>CC</sub> =1.2±0.1V	3.2	6.4	12.3	ns
			V <sub>CC</sub> =1.5±0.1V	2.1	4.5	7.3	ns
			V <sub>CC</sub> =1.8±0.15V	1.9	3.8	5.5	ns
			V <sub>CC</sub> =2.5±0.2V	2.1	3.2	4.2	ns
			V <sub>CC</sub> =3.3±0.3V	1.8	3.0	3.8	ns
		CL=15pF, RL=1MΩ	V <sub>CC</sub> =0.9V	--	24.7	--	ns
			V <sub>CC</sub> =1.2±0.1V	3.6	7.2	14.1	ns
			V <sub>CC</sub> =1.5±0.1V	3.0	5.1	8.1	ns
			V <sub>CC</sub> =1.8±0.15V	2.2	4.3	6.3	ns
			V <sub>CC</sub> =2.5±0.2V	2.0	3.7	4.9	ns
			V <sub>CC</sub> =3.3±0.3V	2.0	3.5	4.4	ns
		CL=30pF, RL=1MΩ	V <sub>CC</sub> =0.9V	--	37.4	--	ns
			V <sub>CC</sub> =1.2±0.1V	4.8	9.5	19	ns
			V <sub>CC</sub> =1.5±0.1V	4.0	6.7	10.8	ns
			V <sub>CC</sub> =1.8±0.15V	2.9	5.6	8.4	ns
			V <sub>CC</sub> =2.5±0.2V	2.7	4.8	6.3	ns
			V <sub>CC</sub> =3.3±0.3V	2.7	4.6	5.8	ns

### TEST CIRCUIT AND WAVEFORMS



	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V} \pm 0.1\text{ V}$	$V_{CC} = 1.5\text{ V} \pm 0.1\text{ V}$	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$	$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$	$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$
$C_L$	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
$V_M$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
$V_I$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$

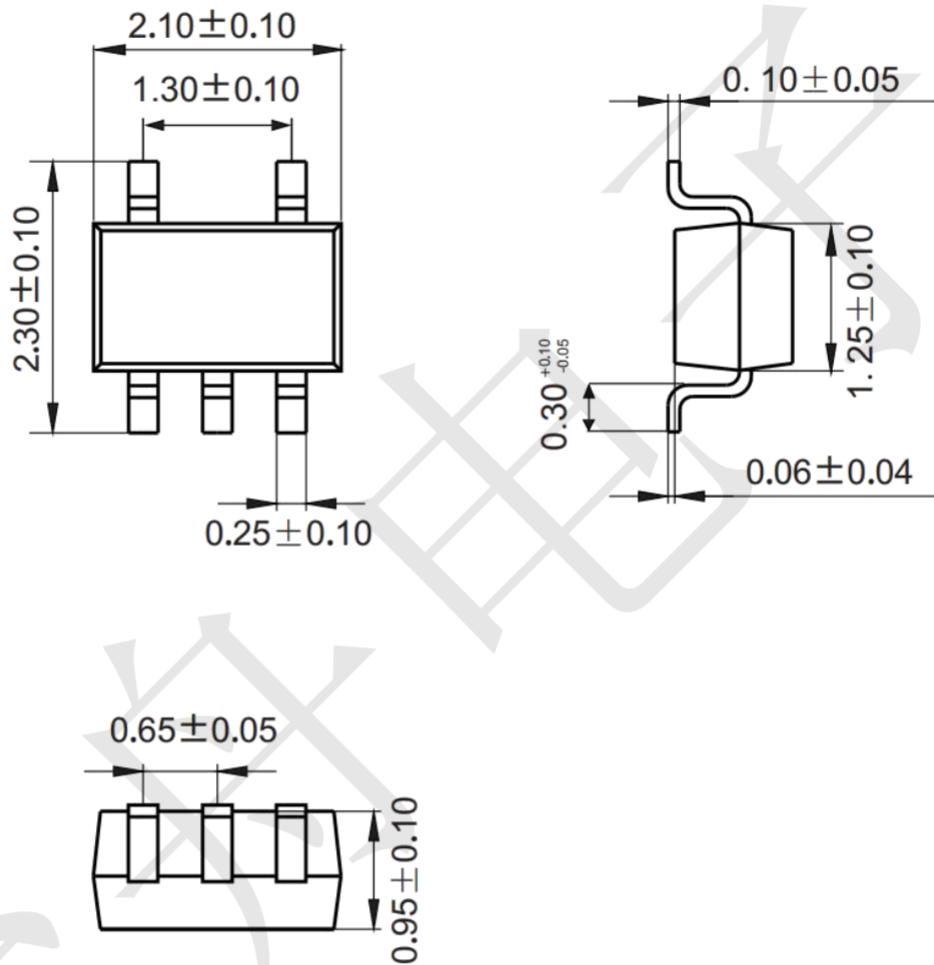


Notes:

1.  $C_L$  includes probe and jig capacitance.
2. All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10\text{ MHz}$ ,  $Z_O = 50\Omega$ .
3. The outputs are measured one at a time, with one transition per measurement.
4.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
5. All parameters and waveforms are not applicable to all devices

**Package information (Unit: mm)**

**SOT353**



**Mounting Pad Layout (unit: mm)**

